



DTA143T

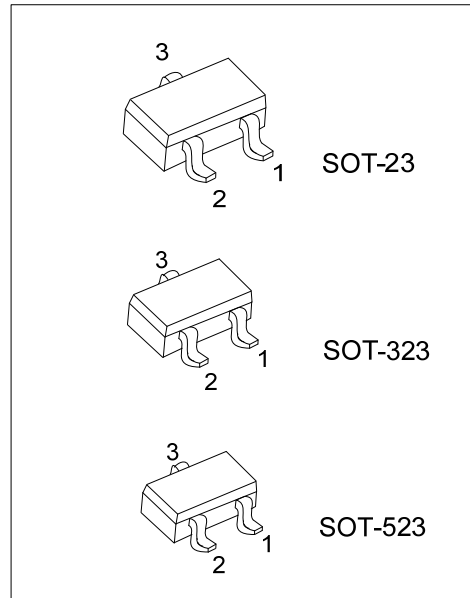
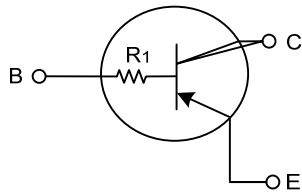
PNP SILICON TRANSISTOR

DIGITAL TRANSISTORS (BUILT-IN BIAS RESISTORS)

■ FEATURES

- * Built-in bias resistors that implies easy ON/OFF applications.
- * The bias resistors are thin-film resistors with complete isolation to allow positive input.

■ EQUIVALENT CIRCUIT



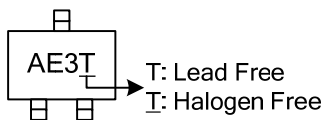
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
DTA143TL-AE3-R	DTA143TG-AE3-R	SOT-23	E	C	B	Tape Reel
DTA143TL-AL3-R	DTA143TG-AL3-R	SOT-323	E	C	B	Tape Reel
DTA143TL-AN3-R	DTA143TG-AN3-R	SOT-523	E	C	B	Tape Reel

Note: Pin Assignment: E: Emitter, B: Base, C: Collector

<p>DTA143TL-AE3-R</p> <p>(1)Packing Type (2)Package Type (3)Lead Free</p>	<p>(1) R: Tape Reel (2) AE3: SOT-23, AL3: SOT-323, AN3: SOT-523 (3) G: Halogen Free, L: Lead Free</p>
---	---

■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C , unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V_{CBO}	-50	V
Collector-Emitter Voltage		V_{CEO}	-50	V
Emitter-Base Voltage		V_{EBO}	-5	V
Collector Current		I_C	-100	mA
Collector Power Dissipation	SOT-23/SOT-323	P_C	200	mW
	SOT-523		150	mW
Junction Temperature		T_J	+150	°C
Storage Temperature		T_{STG}	-40~+150	°C

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged.

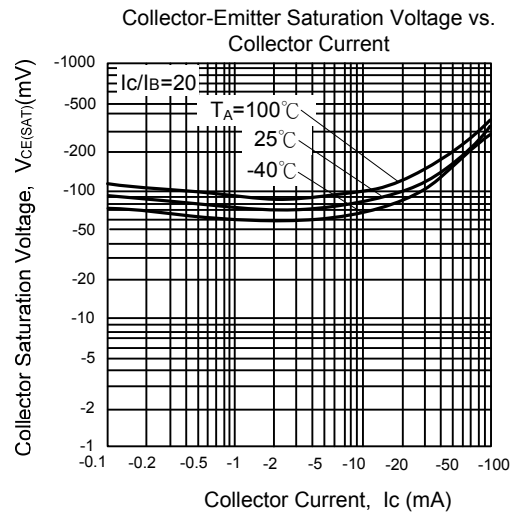
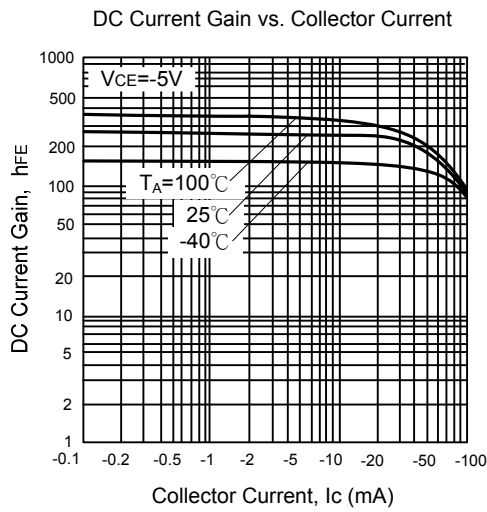
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	BV_{CBO}	$I_C = -50\mu A$	-50			V
Collector-emitter breakdown voltage	BV_{CEO}	$I_C = -1mA$	-50			V
Emitter-base breakdown voltage	BV_{EBO}	$I_E = -50\mu A$	-5			V
Collector cutoff current	I_{CBO}	$V_{CB} = -50V$			-0.5	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = -4V$			-0.5	μA
Collector-emitter saturation voltage	$V_{CE(SAT)}$	$I_C = -5mA, I_B = -0.25mA$			-0.3	V
DC Current Gain	h_{FE}	$V_{CE} = -5V, I_C = -1mA$	100	250	600	
Input resistance	R_1		3.29	4.7	6.11	k Ω
Transition frequency	f_T	$V_{CE} = -10V, I_E = 5mA, f = 100MHz$ (Note)		250		MHz

Note: Transition frequency of the device

■ TYPICAL CHARACTERISTICS



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.